

SCHS167E

Data sheet acquired from Harris Semiconductor

November 1997 - Revised October 2004

CD54/74HC240, CD54/74HCT240, CD74HC241, CD54/74HCT241, CD54/74HC244, CD54/74HCT244

High-Speed CMOS Logic Octal Buffer/Line Drivers, Three-State

Features

- HC/HCT240 Inverting
- HC/HCT241 Non-Inverting
- HC/HCT244 Non-Inverting
- Typical Propagation Delay = 8ns at V_{CC} = 5V, $C_L = 15pF, T_A = 25^{\circ}C$ for HC240
- Three-State Outputs
- Buffered Inputs
- High-Current Bus Driver Outputs
- Fanout (Over Temperature Range)
 - Standard Outputs...... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: $N_{IL} = 30\%$, $N_{IH} = 30\%$ of V_{CC} at $V_{CC} = 5V$
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL} = 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC240 and 'HCT240 are inverting three-state buffers having two active-low output enables. The CD74HC241, 'HCT241, 'HC244 and 'HCT244 are non-inverting threestate buffers that differ only in that the 241 has one activehigh and one active-low output enable, and the 244 has two active-low output enables. All three types have identical pinouts.

Ordering Information

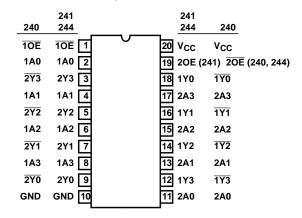
PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC240F3A	-55 to 125	20 Ld CERDIP
CD54HC244F3A	-55 to 125	20 Ld CERDIP
CD54HCT240F3A	-55 to 125	20 Ld CERDIP
CD54HCT241F3A	-55 to 125	20 Ld CERDIP
CD54HCT244F3A	-55 to 125	20 Ld CERDIP
CD74HC240E	-55 to 125	20 Ld PDIP
CD74HC240M	-55 to 125	20 Ld SOIC
CD74HC240M96	-55 to 125	20 Ld SOIC
CD74HC241E	-55 to 125	20 Ld PDIP
CD74HC241M	-55 to 125	20 Ld SOIC
CD74HC241M96	-55 to 125	20 Ld SOIC
CD74HC244E	-55 to 125	20 Ld PDIP
CD74HC244M	-55 to 125	20 Ld SOIC
CD74HC244M96	-55 to 125	20 Ld SOIC
CD74HCT240E	-55 to 125	20 Ld PDIP
CD74HCT240M	-55 to 125	20 Ld SOIC
CD74HCT240M96	-55 to 125	20 Ld SOIC
CD74HCT240PW	-55 to 125	20 Ld TSSOP
CD74HCT240PWR	-55 to 125	20 Ld TSSOP
CD74HCT240PWT	-55 to 125	20 Ld TSSOP
CD74HCT241E	-55 to 125	20 Ld PDIP
CD74HCT241M	-55 to 125	20 Ld SOIC
CD74HCT241M96	-55 to 125	20 Ld SOIC
CD74HCT244E	-55 to 125	20 Ld PDIP
CD74HCT244M	-55 to 125	20 Ld SOIC
CD74HCT244M96	-55 to 125	20 Ld SOIC

NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

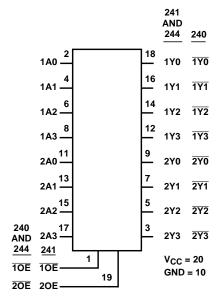
Pinout

CD54HC240, CD54HCT240, CD54HCT241, CD54HC244, CD54HCT244 (CERDIP) CD74HC240, CD74HC241, CD74HCT241, CD74HC244, CD74HCT244 (PDIP, SOIC) CD74HCT240, (PDIP, SOIC, TSSOP)

TOP VIEW



Functional Diagram



Absolute Maximum Ratings

DC Supply Voltage, V $_{CC}$... -0.5V to 7V DC Input Diode Current, I $_{IK}$ For V $_{I}$ < -0.5V or V $_{I}$ > V $_{CC}$ + 0.5V ... ± 20 mA DC Output Diode Current, I $_{OK}$ For V $_{O}$ < -0.5V or V $_{O}$ > V $_{CC}$ + 0.5V ... ± 20 mA DC Drain Current, per Output, I $_{O}$ For -0.5V < V $_{O}$ < V $_{CC}$ + 0.5V ... ± 35 mA DC Output Source or Sink Current per Output Pin, I $_{O}$ For V $_{O}$ > -0.5V or V $_{O}$ < V $_{CC}$ + 0.5V ... ± 25 mA DC V $_{CC}$ or Ground Current, I $_{CC}$... ± 270 mA

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA}
E (PDIP) Package	69°C/W
M (SOIC) Package	58°C/W
PW (TSSOP) Package	83°C/W
Maximum Junction Temperature	150 ^o C
Maximum Storage Temperature Range65 ^o	C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T_A)55°C to 125°C Supply Voltage Range, V_{CC}
HC Types
HCT Types
DC Input or Output Voltage, V _I , V _O
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS			25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads		V_{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Voltage TTL Loads			-7.8	6	5.48	-	-	5.34	-	5.2	-	٧
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	٧
Voltage CMOS Loads		V_{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	٧
			0.02	6	-	-	0.1	-	0.1	-	0.1	٧
Low Level Output	1		6	4.5	-	-	0.26	-	0.33	-	0.4	٧
Voltage TTL Loads			7.8	6	-	-	0.26	-	0.33	-	0.4	٧
Input Leakage Current	II	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	ICC	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ

CD54/74HC240, CD54/74HCT240, CD74HC241, CD54/74HCT241, CD54/74HC244, CD54/74HCT244

DC Electrical Specifications (Continued)

			ST ITIONS			25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Three-State Leakage Current	l _{OZ}	V _{IL} or V _{IH}	-	6	-	-	±0.5	-	±0.5	-	±10	μА
HCT TYPES												
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{ОН}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I _I	V _{CC} to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА
Three-State Leakage Current	l _{OZ}	V _{IL} or V _{IH}	-	5.5	-	-	±0.5	-	±5	-	±10	μА

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
HCT240	
nA0-A3	1.5
10E	0.7
2OE	0.7
HCT241	
nA0-A3	0.7
10E	0.7
20E	1.5
HCT244	
nA0-A3	0.7
10E	0.7
2OE	0.7

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical

Specifications table, e.g., 360 μA max at 25 ^{0}C .

^{2.} For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

CD54/74HC240, CD54/74HCT240, CD74HC241, CD54/74HCT241, CD54/74HC244, CD54/74HCT244

Switching Specifications $C_L = 50pF$, Input t_r , $t_f = 6ns$

		TEST	.,		25°C		-40 ^c	C TO	35°C	-55 ⁰	C TO 1	25°C	
PARAMETER	SYMBOL	CONDI- TIONS	V _{CC} (V)	MIN	ТҮР	МАХ	MIN	TYP	MAX	MIN	TYP	мах	UNITS
HC TYPES													
Propagation Delay Data to Outputs	t _{PLH} , t _{PHL}	C _L = 50pF	2	_	_	100	_	_	125	_	_	150	ns
HC240			4.5	-	-	20	-	-	25	-	-	30	ns
		C _L = 15pF	5	-	8	-	-	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	17	-	-	21	-	-	26	ns
Data to Outputs HC241	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	110	-	-	140	-	-	165	ns
110241			4.5	-	-	22	-	-	28	-	-	33	ns
		C _L = 15pF	5	-	9	-	-	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	19	-	-	24	-	-	28	ns
Data to Outputs HC244	t _{PLH} , t _{PHL}	$C_L = 50pF$	2	-	-	110	-	-	140	-	-	165	ns
110244			4.5	-	-	22	-	-	28	-	-	33	ns
		C _L = 15pF	5	-	9	-	-	-	-	-	-	-	ns
		$C_L = 50pF$	6	-	-	19	-	-	24	-	-	28	ns
Output Enable and Disable Time	t _{THL} , t _{TLH}	$C_L = 50pF$	2	-	-	150	-	-	190	-	-	225	ns
Time			4.5	-	-	30	-	-	38	-	-	45	ns
			5	-	12	-	-	-	-	-	-	-	ns
			6	-	-	26	-	-	33	-	-	38	ns
Output Transition Time	t _{TLH} , t _{THL}	$C_L = 50pF$	2	-	-	60	-	-	75	-	-	90	ns
			4.5	-	-	12	-	-	15	-	-	18	ns
			6	-	-	10	-	-	13	-	-	15	ns
Input Capacitance	Cl	$C_L = 50pF$	-	10	-	10	-	-	10	-	-	10	pF
Three-State Output Capacitance	CO	$C_L = 50pF$	-	-	-	20	-	-	20	-	-	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	C _L = 15pF											
HC240			5	-	38	-	-	-	-	-	-	-	pF
HC241			5	-	34	-	-	-	-	-	-	-	pF
HC244			5	-	46	-	-	-	-	-	-	-	pF
HCT TYPES													
Propagation Delay													
Data to Outputs HCT240	^t PHL, ^t PLH	C _L = 50pF	4.5	-	-	22	-	-	28	-	-	33	ns
		C _L = 15pF	5	-	9	-	-	-	-	-	-	-	ns
Data to Outputs HCT241	^t PHL, ^t PLH	C _L = 50pF	4.5	-	-	25	-	-	31	-	-	38	ns
		C _L = 15pF	5	-	10	-	-	-	-	-	-	-	ns
Data to Outputs HCT244	^t PHL, ^t PLH	C _L = 50pF	4.5	-	-	25	-	-	31	-	-	38	ns
		C _L = 15pF	5	-	10	-	-		-	-			ns

Switching Specifications $C_L = 50pF$, Input t_r , $t_f = 6ns$ (Continued)

		TEST	.,		25°C		-40 ⁰	с то в	35°C	-55°	C TO 1	25°C	
PARAMETER	SYMBOL	CONDI- TIONS	V _{CC}	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Output Enable and Disable Times	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	30	-	-	38	-	-	45	ns
Output Transition Time	t _{THL} , t _{TLH}	C _L = 50pF	4.5	-	-	12	-	-	15	-	-	18	ns
Input Capacitance	Cl	C _L = 50pF	-	10	-	10	-	-	10	-	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}		_		40								
HCT240		-	5	-	40	-			-	-	-	-	pF
HCT241		-	5	-	38	-	-	-	-	-	-	-	pF
HCT244		-	5	-	40	-	-	-	-	-	-	-	pF

NOTES:

- 3. C_{PD} is used to determine the dynamic power consumption, per channel.
- 4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where $f_i = Input$ Frequency, $f_O = Output$ Frequency, $C_L = Output$ Load Capacitance, $V_{CC} = Supply$ Voltage.

Test Circuits and Waveforms

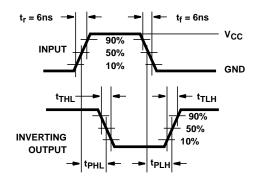


FIGURE 1. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

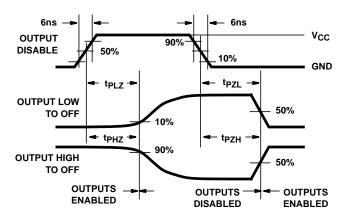


FIGURE 3. HC THREE-STATE PROPAGATION DELAY WAVEFORM

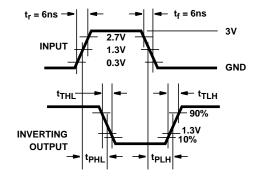


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

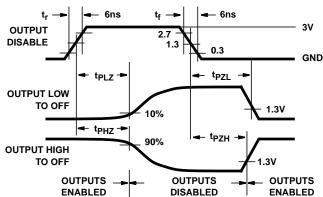
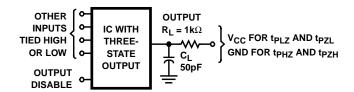


FIGURE 4. HCT THREE-STATE PROPAGATION DELAY WAVEFORM

Test Circuits and Waveforms (Continued)



NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 5. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT





24-Aug-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CD54HC240F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	8407401RA CD54HC240F3A	Samples
CD54HC244F	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HC244F	Samples
CD54HC244F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	8409601RA CD54HC244F3A	Samples
CD54HCT240F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	8550501RA CD54HCT240F3A	Samples
CD54HCT241F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HCT241F3A	Samples
CD54HCT244F	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HCT244F	Samples
CD54HCT244F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	8513001RA CD54HCT244F3A	Samples
CD74HC240E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC240E	Samples
CD74HC240M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC240M	Samples
CD74HC240M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC240M	Samples
CD74HC241E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC241E	Samples
CD74HC241M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC241M	Samples
CD74HC241M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC241M	Samples
CD74HC241M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC241M	Samples
CD74HC241MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC241M	Samples
CD74HC244E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC244E	Samples
CD74HC244EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC244E	Samples



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
CD74HC244M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC244M	Sample
CD74HC244M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC244M	Sample
CD74HC244M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC244M	Sample
CD74HC244M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC244M	Sample
CD74HCT240E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT240E	Sample
CD74HCT240EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT240E	Sample
CD74HCT240M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT240M	Sample
CD74HCT240M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT240M	Sample
CD74HCT240MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT240M	Sample
CD74HCT240PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HK240	Sample
CD74HCT240PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HK240	Sample
CD74HCT240PWT	ACTIVE	TSSOP	PW	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HK240	Sample
CD74HCT241E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT241E	Sample
CD74HCT241EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT241E	Sample
CD74HCT241M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT241M	Sample
CD74HCT241M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT241M	Sample
CD74HCT244E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT244E	Sample
CD74HCT244M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT244M	Sample



PACKAGE OPTION ADDENDUM

24-Aug-2018

Orderable Device	Status	Package Type	Package Drawing	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Diawing		Qty	(2)	(6)	(3)		(4/5)	
CD74HCT244M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT244M	Samples
CD74HCT244ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT244M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD54HC240, CD54HC244, CD54HCT240, CD54HCT241, CD54HCT244, CD74HC240, CD74HC244, CD74HCT240, CD74HCT241, CD74HCT244:



PACKAGE OPTION ADDENDUM

24-Aug-2018

- Catalog: CD74HC240, CD74HC244, CD74HCT240, CD74HCT241, CD74HCT244
- Military: CD54HC240, CD54HC244, CD54HCT240, CD54HCT241, CD54HCT244

NOTE: Qualified Version Definitions:

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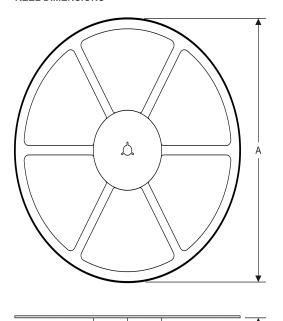
- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

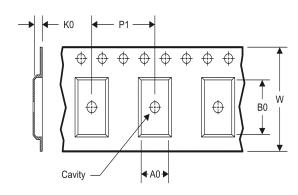
www.ti.com 14-Jul-2012

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC240M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CD74HC241M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CD74HC244M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CD74HCT240M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CD74HCT240PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
CD74HCT240PWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
CD74HCT241M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CD74HCT244M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1

www.ti.com 14-Jul-2012



*All dimensions are nominal

Device	Bookaga Typa	Bookaga Drawing	Pins	SPQ	Longth (mm)	Width (mm)	Hoight (mm)
Device	Package Type	Package Drawing	FIIIS	SFU	Length (mm)	widin (min)	Height (mm)
CD74HC240M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HC241M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HC244M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HCT240M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HCT240PWR	TSSOP	PW	20	2000	367.0	367.0	38.0
CD74HCT240PWT	TSSOP	PW	20	250	367.0	367.0	38.0
CD74HCT241M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HCT244M96	SOIC	DW	20	2000	367.0	367.0	45.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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